

High Speed, Dual MOSFET Driver

Features

- ❑ 6.0ns rise and fall time with 1000pF load
- ❑ 2.0A peak output source/sink current
- ❑ 1.2V to 5V input CMOS compatible
- ❑ 4.5V to 13V total supply voltage
- ❑ Smart Logic threshold
- ❑ Low jitter design
- ❑ Dual matched channels
- ❑ Outputs can swing below ground
- ❑ Low inductance package
- ❑ Thermally-enhanced package

Applications

- ❑ Medical ultrasound imaging
- ❑ Piezoelectric transducer drivers
- ❑ Nondestructive evaluation
- ❑ PIN diode driver
- ❑ Clock driver/buffer
- ❑ High speed level translator

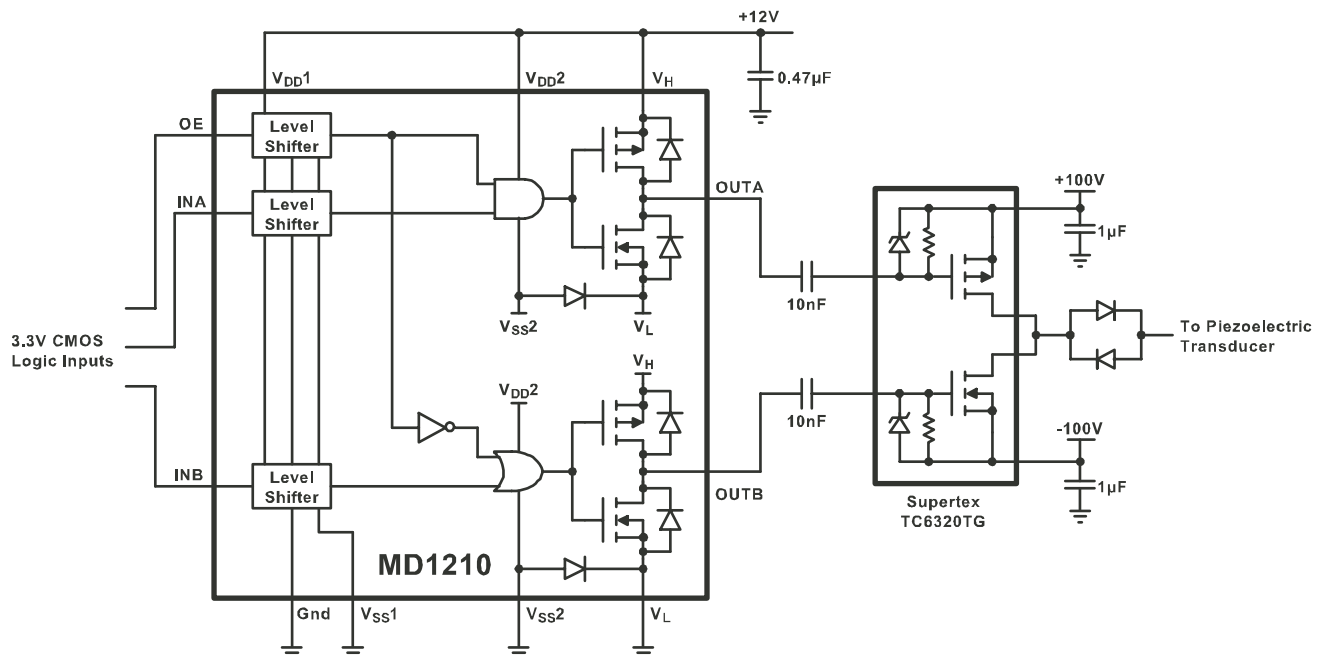
General Description

The Supertex MD1210 is a high speed, dual MOSFET driver. It is designed to drive high voltage N- and P-channel MOSFET transistors for medical ultrasound applications and other application requiring a high output current for a capacitive load. The high-speed input stage of the MD1210 can operate from 1.2 to 5.0 volt logic interface with an optimum operating input signal range of 1.8 to 3.3 volts. An adaptive threshold circuit is used to set the level translator switch threshold to the average of the input logic 0 and logic 1 levels. The input logic levels may be ground referenced, even though the driver is putting out bipolar signals. The level translator uses a proprietary circuit, which provides DC coupling together with high-speed operation.

The output stage of the MD1210 has separate power connections enabling the output signal L and H levels to be chosen independently from the supply voltages used for the majority of the circuit. As an example, the input logic levels may be 0 and 1.8 volts, the control logic may be powered by +5.0 and -5.0 volts, and the output L and H levels may be varied anywhere over the range of -5.0 to +5.0 volts. The output stage is capable of peak currents of up to ±2.0 amps, depending on the supply voltages used and load capacitance present.

The OE pin serves a dual purpose. First, its logic H level is used to compute the threshold voltage level for the channel input level translators. Secondly, when OE is low, the outputs are disabled, with the A output high and the B output low. This assists in properly pre-charging the AC coupling capacitors that may be used in series in the gate drive circuit of an external PMOS and NMOS transistor pair.

Typical Application Circuit



NR013105

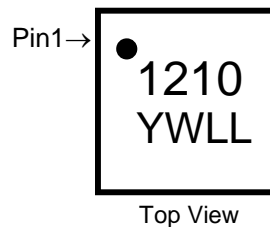
Ordering Information

Device	Package Option
	12-lead 4x4x0.9 QFN
MD1210	MD1210K6

Product Marking Information		
1 st line	1210	Device Number
2 nd line	YWLL	Year, Week Code, Lot Number
Example: 5A88 means Lot #88 of first or second week in 2005		

Absolute Maximum Ratings*

$V_{DD}-V_{SS}$, Logic Supply Voltage	-0.5V to +13.5V
V_H , Output High Supply Voltage	$V_L-0.5V$ to $V_{DD}+0.5V$
V_L , Output Low Supply Voltage	$V_{SS}-0.5V$ to $V_H+0.5V$
V_{SS} , Low Side Supply Voltage	-7.0V to +0.5V
Logic Input Levels	$V_{SS}-0.5V$ to $V_{SS}+7.0V$
Maximum Junction Temperature	+125°C
Storage Temperature	-65°C to 150°C



*Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

DC Electrical Characteristics

(Over operating conditions unless otherwise specified, $V_H=V_{DD1}=V_{DD2}=12V$, $V_L=V_{SS1}=V_{SS2}=0V$, $V_{OE}=3.3V$, $T_J=25^\circ C$)

Sym	Parameter	Min	Typ	Max	Units	Conditions
$V_{DD}-V_{SS}$	Logic supply voltage	4.5		13	V	
V_{SS}	Low side supply voltage	-5.5		0	V	
V_H	Output high supply voltage	$V_{SS}+2.0$		V_{DD}	V	
V_L	Output low supply voltage	V_{SS}		$V_{DD}-2$	V	
I_{DD1Q}	V_{DD1} quiescent current		0.55		mA	No input transitions
I_{DD2Q}	V_{DD2} quiescent current			10	μA	
I_{HQ}	V_H quiescent current			10	μA	
I_{DD1}	V_{DD1} average current		0.88		mA	One channel on at 5.0Mhz, No load
I_{DD2}	V_{DD2} average current		6.6		mA	
I_H	V_H average current		23		mA	
V_{IH}	Input logic voltage high	$V_{OE}-0.3$		5.0	V	For logic inputs INA and INB.
V_{IL}	Input logic voltage low	0		0.3	V	
I_{IH}	Input logic current high			1.0	μA	
I_{IL}	Input logic current low			1.0	μA	
V_{IH}	OE Input logic voltage high	1.2		5.0	V	For logic input OE
V_{IL}	OE Input logic voltage low	0		0.3	V	
R_{IN}	Input logic impedance to GND	12	20	30	K Ω	
C_{IN}	Logic input capacitance		5.0	10	pF	All Inputs
θ_{JA}	Thermal resistance to air		47		$^\circ C/W$	1oz. 4-layer 3x4inch PCB with thermal pad and thermal via array.
θ_{JC}	Thermal resistance to case		7.0		$^\circ C/W$	

Outputs ($V_H=V_{DD1}=V_{DD2}=12V$, $V_L=V_{SS1}=V_{SS2}=0V$, $V_{OE}=3.3V$, $T_J=25^\circ C$)

Sym	Parameter	Min	Typ	Max	Units	Conditions
R_{SINK}	Output sink resistance			12.5	Ω	$I_{SINK}=50mA$
R_{SOURCE}	Output source resistance			12.5	Ω	$I_{SOURCE}=50mA$
I_{SINK}	Peak output sink current		2.0		A	
I_{SOURCE}	Peak output source current		2.0		A	

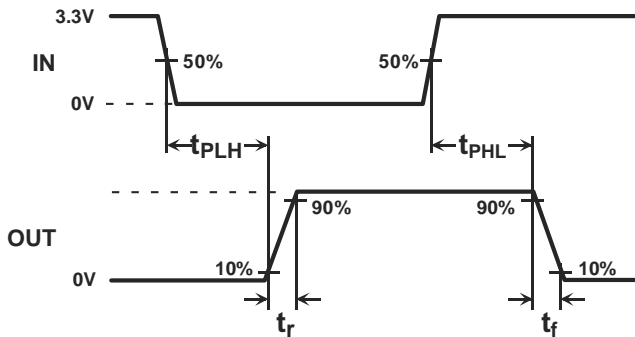
AC Electrical Characteristics ($V_{IH}=V_{DD1}=V_{DD2}=12V$, $V_L=V_{SS1}=V_{SS2}=0V$, $V_{OE}=3.3V$, $T_J=25^\circ C$)

Sym	Parameter	Min	Typ	Max	Units	Conditions
t_{irf}	Inputs or OE rise & fall time			10	ns	Logic input edge speed requirement
t_{PLH}	Propagation delay when output is from low to high		7.0		ns	No load, see timing diagram Input signal rise/fall time 2ns
t_{PHL}	Propagation delay when output is from high to low		7.0		ns	
t_{POE}	Propagation delay OE to outputs		9.0		ns	
t_r	Output rise time		6.0		ns	$C_{LOAD}=1000pF$, see timing diagram Input signal rise/fall time 2ns
t_f	Output fall time		6.0		ns	
$ t_r - t_f $	Rise and fall time matching		1.0	TBD	ns	
$ t_{PLH} - t_{PHL} $	Propagation low to high and high to low matching		1.0		ns	
Δt_{dm}	Propagation delay Match		± 2.0	TBD	ns	Device to device delay match

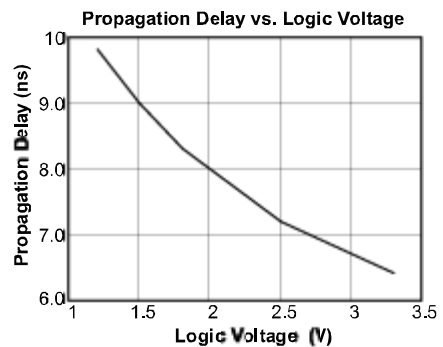
Logic Truth Table

Logic Inputs			Output	
OE	INA	INB	OUTA	OUTB
H	L	L	V_H	V_H
H	L	H	V_H	V_L
H	H	L	V_L	V_H
H	H	H	V_L	V_L
L	X	X	V_H	V_L

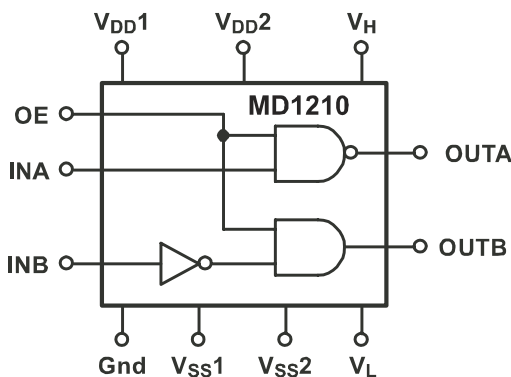
Timing Diagram



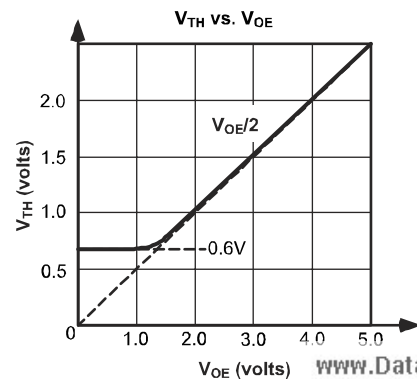
Propagation Delay



Simplified Block Diagram



Logic Input Threshold

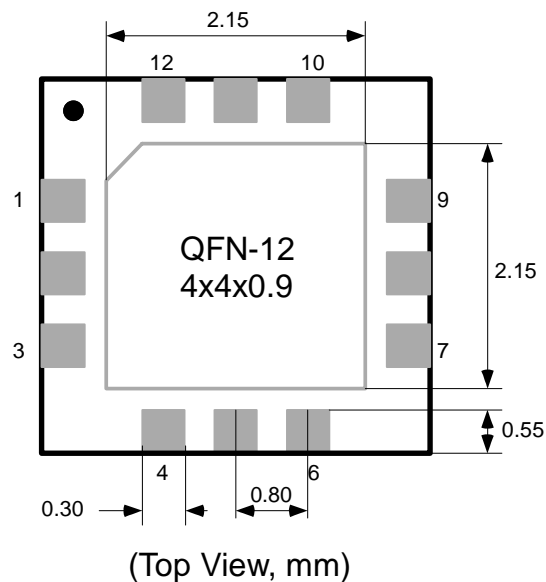


Pin Description

V _{DD1}	High side analog circuit and level shifter supply voltage. Should be at the same potential as V _{DD2} .
V _{DD2}	High side gate drive supply voltage
V _{SS1}	Low side analog circuit and level shifter supply voltage. Should be at the same potential as V _{SS2} .
V _{SS2}	Low side gate drive supply voltage
V _H	Supply voltage for P-channel output stage
V _L	Supply voltage for N-channel output stage
GND	Logic input ground reference
OE	Output-enable logic input. When OE is high, $(V_{OE}+V_{GND})/2$ sets the threshold transition between logic level high and low for INA and INB. When OE is low, OUTA is at V _H and OUTB is at V _L regardless of INA and INB.
INA	Logic input. Controls OUTA when OE is high. Input logic high will cause the output to swing to V _L . Input logic low will cause the output to swing to V _H .
INB	Logic input. Controls OUTB when OE is high. Input logic high will cause the output to swing to V _L . Input logic low will cause the output to swing to V _H .
OUTA	Output driver. Swings from V _H to V _L . Intended to drive the gate of an external P-channel MOSFET via a series capacitor. When OE is low, the output is disabled. OUTA will swing to V _H turning off the external P-channel MOSFET.
OUTB	Output driver. Swings from V _H to V _L . Intended to drive the gate of an external N-channel MOSFET via a series capacitor. When OE is low, the output is disabled. OUTB will swing to V _L turning off the external N-channel MOSFET.

Pin Configuration

Pin #	Function
1	INA
2	V _L
3	INB
4	GND
5	V _{SS1}
6	V _{SS2}
7	OUTB
8	V _H
9	OUTA
10	V _{DD2}
11	V _{DD1}
12	OE
Note	Thermal Pad, and substrate are connected to Pin#5, V _{SS1}



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